

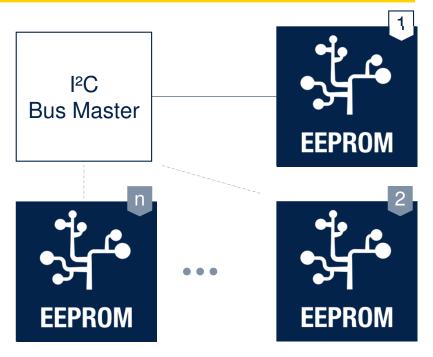
Discover the M24256E-F

The 256Kbit I²C EEPROM in SO8N from new process

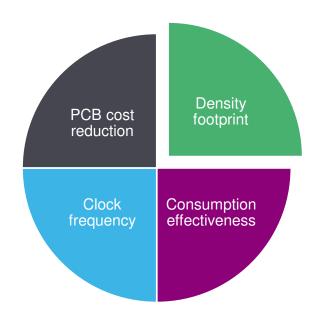


Two main new features

1. Multiple EEPROMs on same bus

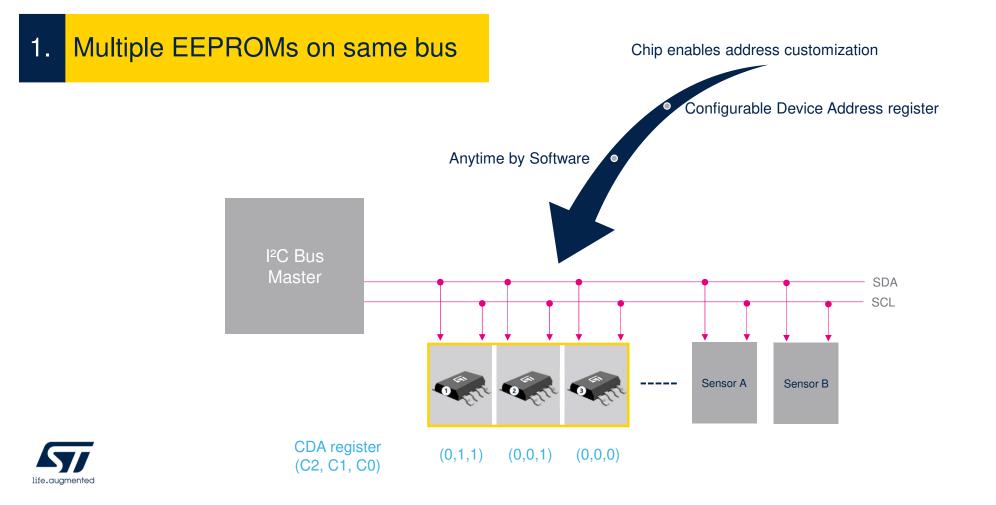


2. Enhanced technology process



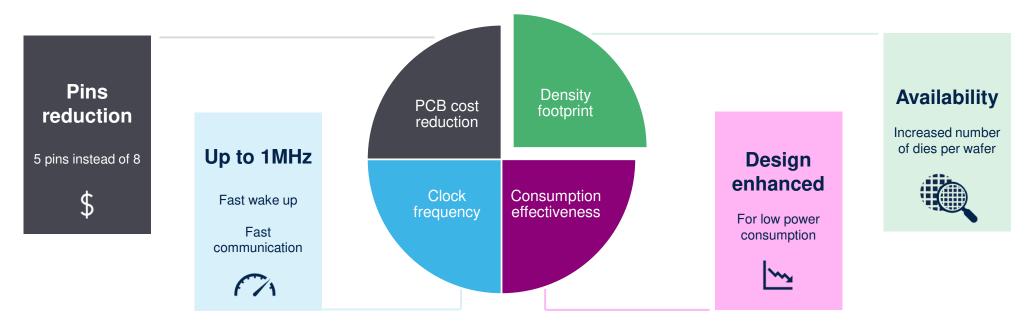


Configurable device address



New customer offer

2. Enhanced technology process





Key features

Fast wake-up & communication, low supply



- 256Kbit memory organized as 32Kbytes
- SO8N JEDEC package 4.9 x 6 mm
- Fast-mode Plus (1MHz) across 1.6 V to 5.5 V
- Temperature range -40°C up to +85°C
- 64 bytes per page
- 5ms for byte and page write
- 4 Million write cycles at 25°C
- 200-year data retention
- ESD HBM 4000V



Where you find the M24256E-F typical applications











Additional resources



Find out more on M24256E-F product page and apply for samples



Download the <u>datasheet</u>



Our technology starts with You



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